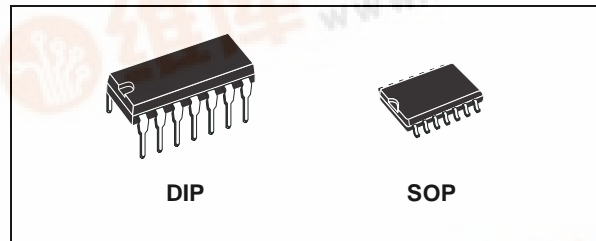




HCF4093B

QUAD 2 INPUT NAND SCHMITT TRIGGER

- SCHMITT TRIGGER ACTION ON EACH INPUT WITH NO EXTERNAL COMPONENTS
- HYSTERESIS VOLTAGE TYPICALLY 0.9V at $V_{DD} = 5V$ AND 2.3V at $V_{DD} = 10V$
- NOISE IMMUNITY GREATER THAN 50% OF V_{DD} (Typ.)
- NO LIMIT ON INPUT RISE AND FALL TIMES
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- 5V, 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT
 $I_l = 100nA$ (MAX) AT $V_{DD} = 18V$ $T_A = 25^\circ C$
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B "STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



ORDER CODES

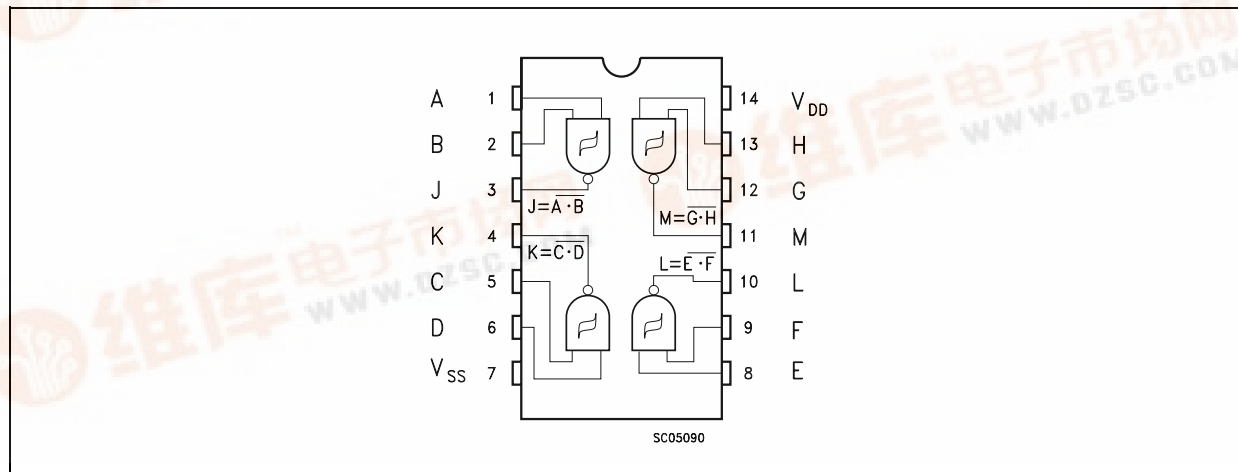
PACKAGE	TUBE	T & R
DIP	HCF4093BEY	
SOP	HCF4093BM1	HCF4093M013TR

DESCRIPTION

The HCF4093B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages.

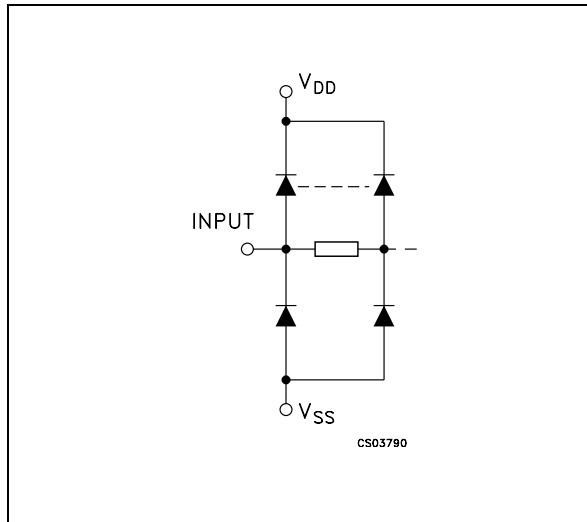
The HCF4093B type consists of four schmitt trigger circuits. Each circuit functions as a two input NAND gate with schmitt trigger action on both inputs. The gate switches at different points for positive and negative going signals. The difference between the positive voltage (V_P) and the negative voltage (V_N) is defined as hysteresis voltage (V_H).

PIN CONNECTION



HCF4093B

INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 2, 5, 6, 8, 9, 12, 13	A, B, C, D, E, F, G, H	Data Inputs
3, 4, 10, 11	J, K, L, M	Data Outputs
7	V _{SS}	Negative Supply Voltage
14	V _{DD}	Positive Supply Voltage

TRUTH TABLE

INPUTS		OUTPUTS
A, C, E, G	B, D, F, H	J, K, L, M
L	L	H
L	H	H
H	L	H
H	H	L

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	-0.5 to +22	V
V _I	DC Input Voltage	-0.5 to V _{DD} + 0.5	V
I _I	DC Input Current	± 10	mA
P _D	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T _{op}	Operating Temperature	-55 to +125	°C
T _{stg}	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V_{SS} pin voltage.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{DD}	Supply Voltage	3 to 20	V
V _I	Input Voltage	0 to V _{DD}	V
T _{op}	Operating Temperature	-55 to 125	°C

DC SPECIFICATIONS

Symbol	Parameter	Test Condition				Value						Unit	
		V _I (V)	V _O (V)	I _{OL} (μ A)	V _{DD} (V)	T _A = 25°C			-40 to 85°C		-55 to 125°C		
						Min.	Typ.	Max.	Min.	Max.	Min.		Max.
I _L	Quiescent Current	0/5			5		0.02	1		30		30	μ A
		0/10			10		0.02	2		60		60	
		0/15			15		0.02	4		120		120	
		0/20			20		0.04	20		600		600	
V _{OH}	High Level Output Voltage	0/5		<1	5	4.95			4.95		4.95		V
		0/10		<1	10	9.95			9.95		9.95		
		0/15		<1	15	14.95			14.95		14.95		
V _{OL}	Low Level Output Voltage	5/0		<1	5		0.05			0.05		0.05	V
		10/0		<1	10		0.05			0.05		0.05	
		15/0		<1	15		0.05			0.05		0.05	
V _P	Positive Trigger Threshold Voltage	a			5	2.2	2.9	3.6	2.2	3.6	2.2	3.6	V
		a			10	4.6	5.9	7.1	4.6	7.1	4.6	7.1	
		a			15	6.8	8.8	10.8	6.8	10.8	6.8	10.8	
		b			5	2.6	3.3	4.0	2.6	4	2.6	4	
		b			10	5.6	7	8.2	5.6	8.2	5.6	8.2	
		b			15	6.3	9.4	12.7	6.3	12.7	6.3	12.7	
V _N	Negative Trigger Threshold Voltage	a			5	0.9	1.9	2.8	0.9	2.8	0.9	2.8	V
		a			10	2.5	3.9	5.2	2.5	5.2	2.5	5.2	
		a			15	4	5.8	7.4	4	7.4	4	7.4	
		b			5	1.4	2.3	3.2	1.4	3.2	1.4	3.2	
		b			10	3.4	5.1	6.6	3.4	6.6	3.4	6.6	
		b			15	4.8	7.3	9.6	4.8	9.6	4.8	9.6	
V _H	Hysteresis Voltage	a			5	0.3	0.9	1.6	0.3	1.6	0.3	1.6	V
		a			10	1.2	2.3	3.4	1.2	3.4	1.2	3.4	
		a			15	1.6	3.5	5	1.6	5	1.6	5	
		b			5	0.3	0.9	1.6	0.3	1.6	0.3	1.6	
		b			10	1.2	2.3	3.4	1.2	3.4	1.2	3.4	
		b			15	1.6	3.5	5	1.6	5	1.6	5	
I _{OH}	Output Drive Current	0/5	2.5	<1	5	-1.36	-3.2		-1.15		-1.1		mA
		0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		
		0/15	13.5	<1	15	-3.0	-6.8		-2.4		-2.4		
I _{OL}	Output Sink Current	0/5	0.4	<1	5	0.44	1		0.36		0.36		mA
		0/10	0.5	<1	10	1.1	2.6		0.9		0.9		
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
I _I	Input Leakage Current	0/18	Any Input	18		$\pm 10^{-5}$	± 0.1			± 1		± 1	μ A
C _I	Input Capacitance		Any Input			5	7.5						pF

The Noise Margin for both "1" and "0" level is: 1V min. with V_{DD}=5V, 2V min. with V_{DD}=10V, 2.5V min. with V_{DD}=15V

a : Input on terminals 1, 5, 8, 12 or 2, 6, 9, 13; other inputs to V_{DD}.

b : Input on terminals 1 and 2, 5 and 6, 8 and 9, or 12 and 13; other inputs to V_{DD}.

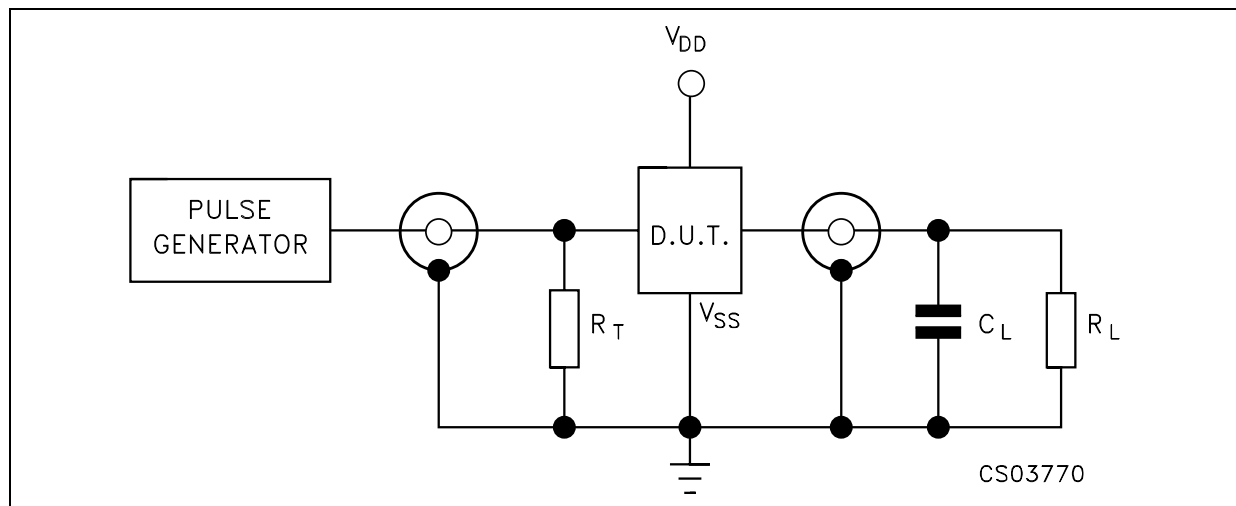
HCF4093B

DYNAMIC ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, $C_L = 50pF$, $R_L = 200K\Omega$, $t_r = t_f = 20 ns$)

Symbol	Parameter	Test Condition		Value (*)			Unit
		V_{DD} (V)		Min.	Typ.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time	5			190	380	ns
		10			90	180	
		15			65	130	
t_{TLH} t_{THL}	Output Transition Time	5			100	200	ns
		10			50	100	
		15			40	80	

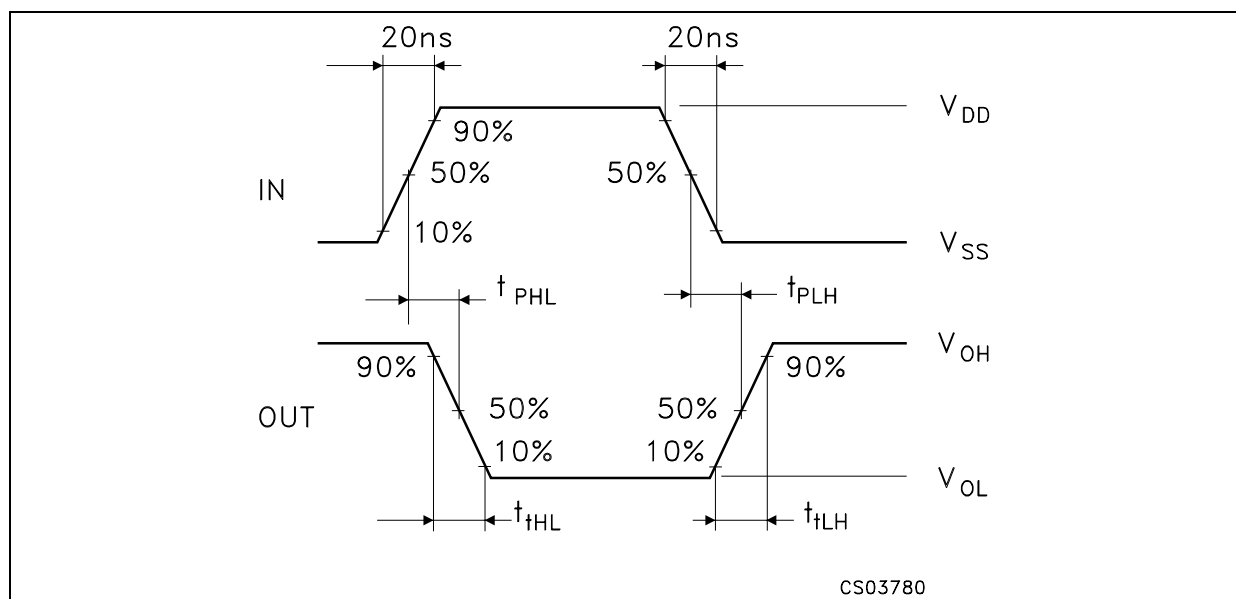
(*) Typical temperature coefficient for all V_{DD} value is 0.3 %/°C.

TEST CIRCUIT



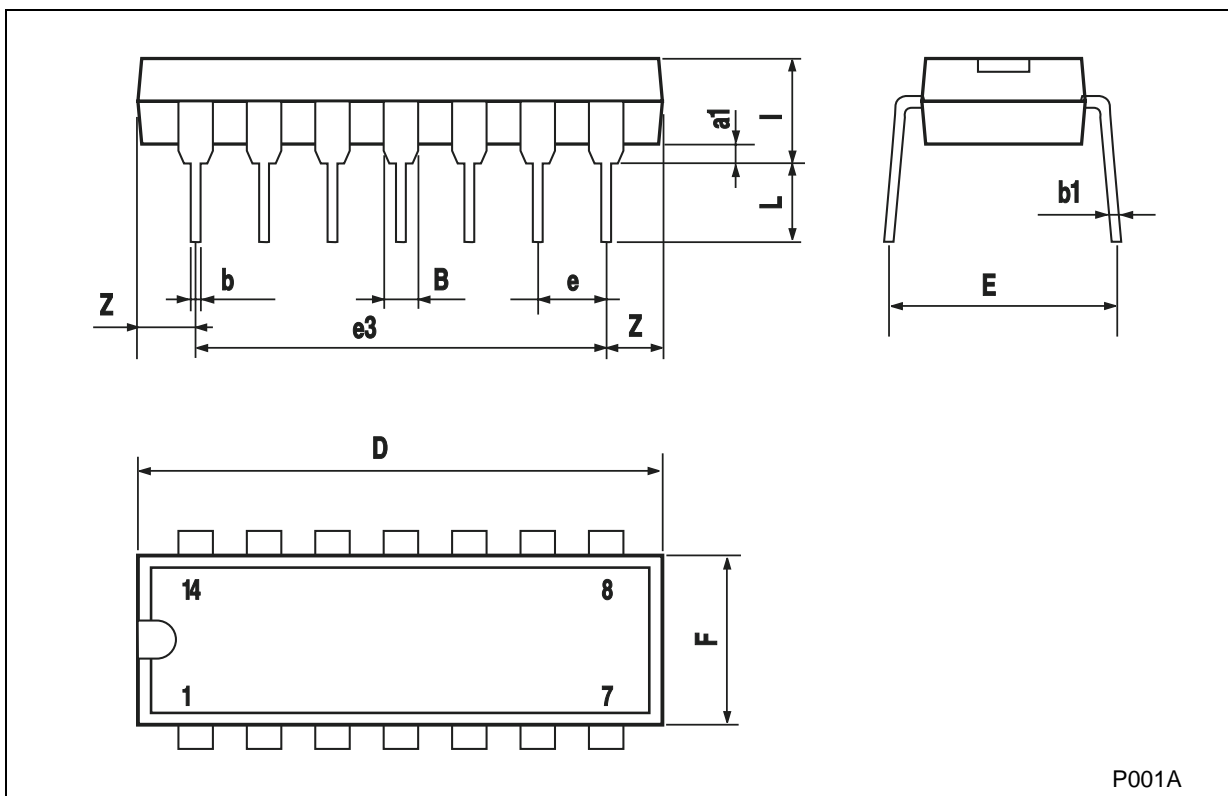
$C_L = 50pF$ or equivalent (includes jig and probe capacitance)
 $R_L = 200K\Omega$
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM : PROPAGATION DELAY TIMES ($f=1MHz$; 50% duty cycle)



Plastic DIP-14 MECHANICAL DATA

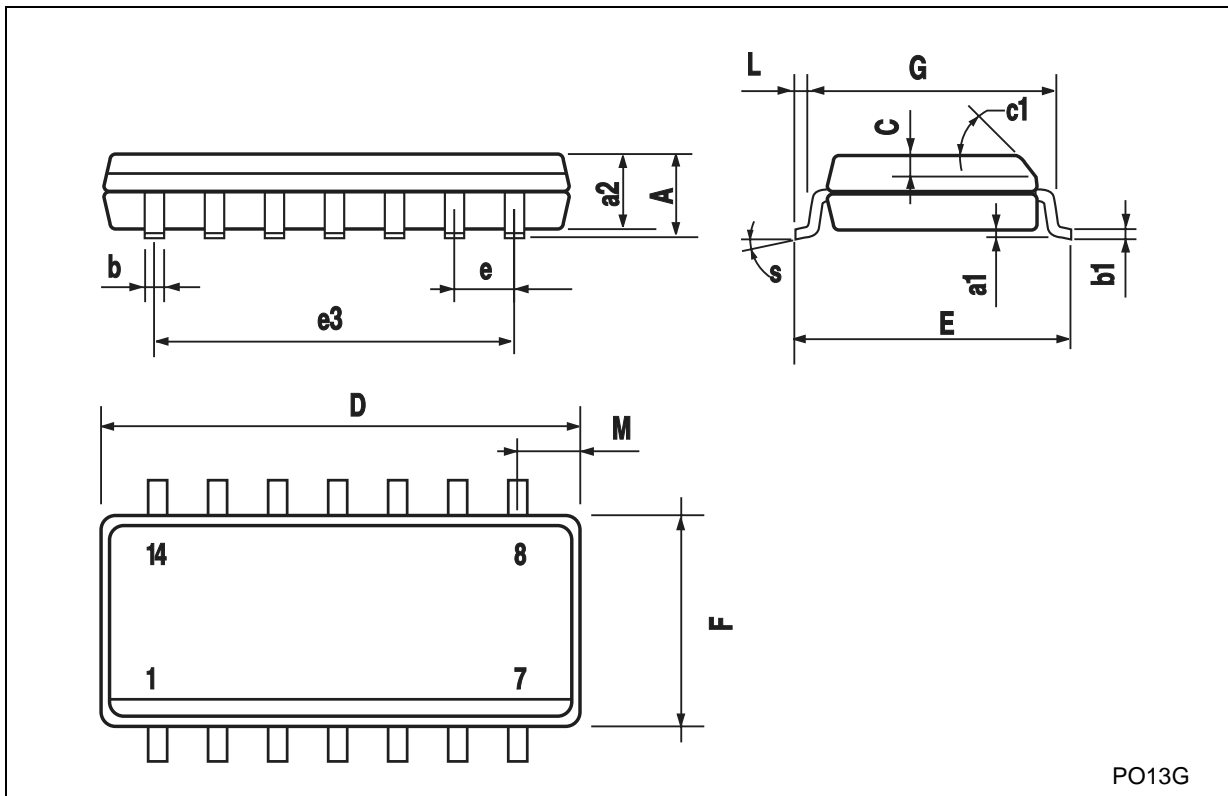
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
l			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



P001A

SO-14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



PO13G

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